



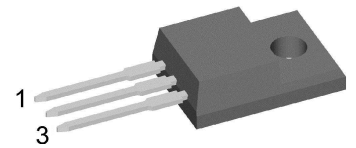
# Schottky Diode

$V_{RRM} = 60\text{ V}$   
 $I_{FAV} = 2 \times 10\text{ A}$   
 $V_F = 0.7\text{ V}$

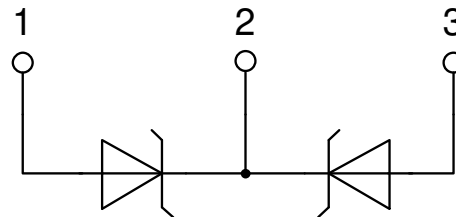
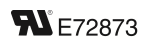
High Performance Schottky Diode  
 Low Loss and Soft Recovery  
 Common Cathode

Part number

**DSA20C60PN**



Backside: isolated



**Features / Advantages:**

- Very low  $V_f$
- Extremely low switching losses
- Low  $I_{rm}$  values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

**Applications:**

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

**Package: TO-220FP**

- Isolation Voltage: 2500 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Soldering pins for PCB mounting
- Base plate: Plastic overmolded tab
- Reduced weight

**Disclaimer Notice**

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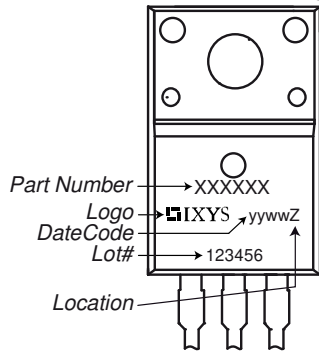


Schottky				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
$V_{RSM}$	max. non-repetitive reverse blocking voltage					60	V
$V_{RRM}$	max. repetitive reverse blocking voltage					60	V
$I_R$	reverse current, drain current	$V_R = 60\text{ V}$		$T_{VJ} = 25^\circ\text{C}$		200	$\mu\text{A}$
		$V_R = 60\text{ V}$		$T_{VJ} = 125^\circ\text{C}$		2	mA
$V_F$	forward voltage drop	$I_F = 10\text{ A}$		$T_{VJ} = 25^\circ\text{C}$		0.86	V
		$I_F = 20\text{ A}$				1.04	V
		$I_F = 10\text{ A}$		$T_{VJ} = 125^\circ\text{C}$		0.70	V
		$I_F = 20\text{ A}$				0.86	V
$I_{FAV}$	average forward current	$T_C = 140^\circ\text{C}$	rectangular	$T_{VJ} = 175^\circ\text{C}$		10	A
$V_{F0}$	threshold voltage	} for power loss calculation only				0.48	V
$r_F$	slope resistance					13.5	m $\Omega$
$R_{thJC}$	thermal resistance junction to case					4.5	K/W
$R_{thCH}$	thermal resistance case to heatsink			0.50			K/W
$P_{tot}$	total power dissipation			$T_C = 25^\circ\text{C}$		35	W
$I_{FSM}$	max. forward surge current	$t = 10\text{ ms}; (50\text{ Hz}), \text{ sine}; V_R = 0\text{ V}$		$T_{VJ} = 45^\circ\text{C}$		240	A
$C_J$	junction capacitance	$V_R = 12\text{ V}$ $f = 1\text{ MHz}$		$T_{VJ} = 25^\circ\text{C}$		149	pF



Package TO-220FP		Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit
$I_{RMS}$	RMS current	per terminal			35	A
$T_{VJ}$	virtual junction temperature		-55		175	°C
$T_{op}$	operation temperature		-55		150	°C
$T_{stg}$	storage temperature		-55		150	°C
<b>Weight</b>				2		g
$M_D$	mounting torque		0.4		0.6	Nm
$F_C$	mounting force with clip		20		60	N
$d_{Spp/App}$	creepage distance on surface   striking distance through air	terminal to terminal	1.6	1.0		mm
$d_{Spb/Apb}$		terminal to backside	2.5	2.5		mm
$V_{ISOL}$	isolation voltage	t = 1 second	2500			V
		t = 1 minute	2100			V

**Product Marking**



**Part description**

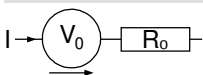
- D = Diode
- S = Schottky Diode
- A = low VF
- 20 = Current Rating [A]
- C = Common Cathode
- 60 = Reverse Voltage [V]
- PN = TO-220ABFP (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA20C60PN	DSA20C60PN	Tube	50	504876

**Equivalent Circuits for Simulation**

\* on die level

$T_{VJ} = 175^{\circ}C$

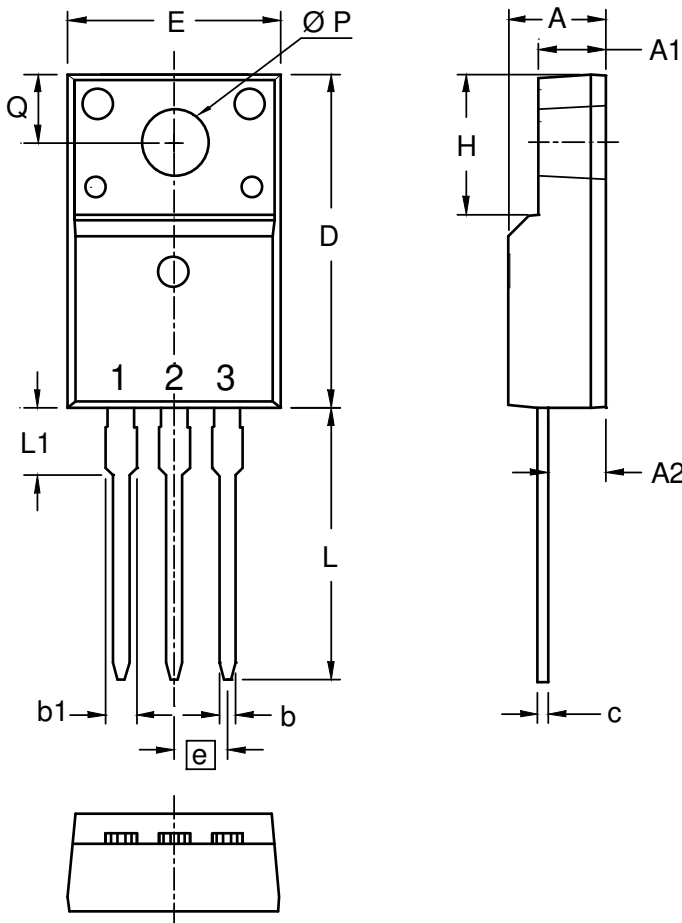


**Schottky**

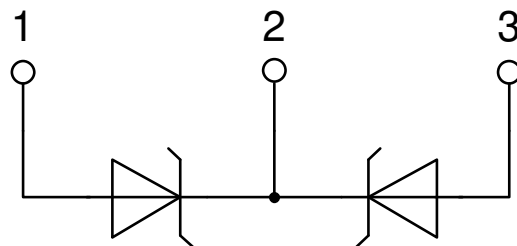
$V_{0\ max}$	threshold voltage	0.48	V
$R_{0\ max}$	slope resistance *	10.3	mΩ



**Outlines TO-220FP**



Dim.	Millimeters		Inches	
	min	max	min	max
A	4.50	4.90	0.177	0.193
A1	2.34	2.74	0.092	0.108
A2	2.56	2.96	0.101	0.117
b	0.70	0.90	0.028	0.035
c	0.45	0.60	0.018	0.024
D	15.67	16.07	0.617	0.633
E	9.96	10.36	0.392	0.408
e	2.54 BSC		0.100 BSC	
H	6.48	6.88	0.255	0.271
L	12.68	13.28	0.499	0.523
L1	3.03	3.43	0.119	0.135
ØP	3.08	3.28	0.121	0.129
Q	3.20	3.40	0.126	0.134





**Schottky**

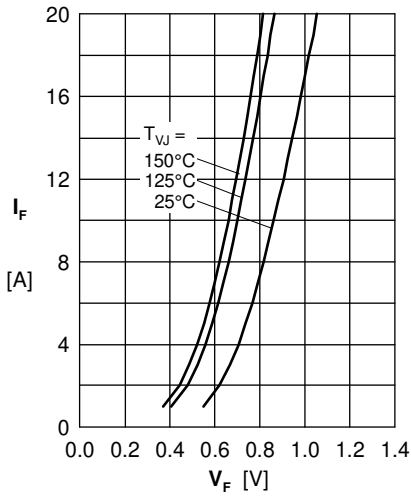


Fig. 1 Maximum forward voltage drop characteristics

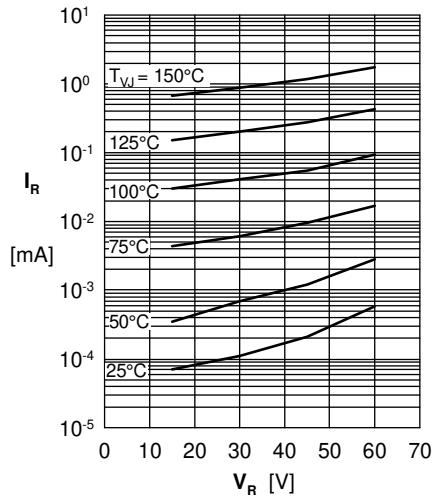


Fig. 2 Typ. reverse current  $I_R$  vs. reverse voltage  $V_R$

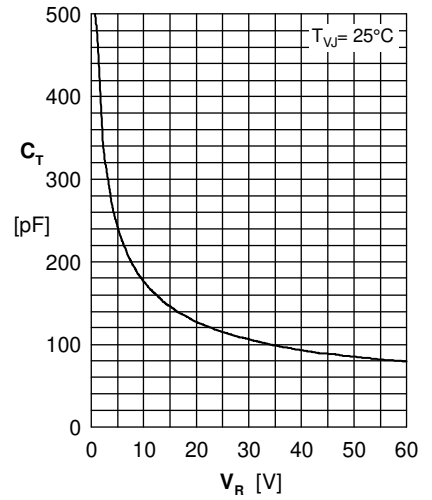


Fig. 3 Typ. junction capacitance  $C_T$  versus reverse voltage  $V_R$

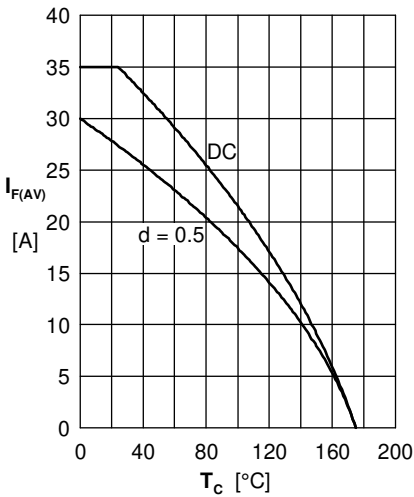


Fig. 4 Avg: forward current  $I_{F(AV)}$  vs. case temperature  $T_C$

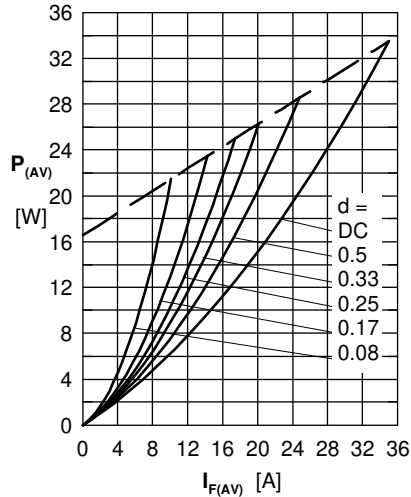


Fig. 5 Forward power loss characteristics

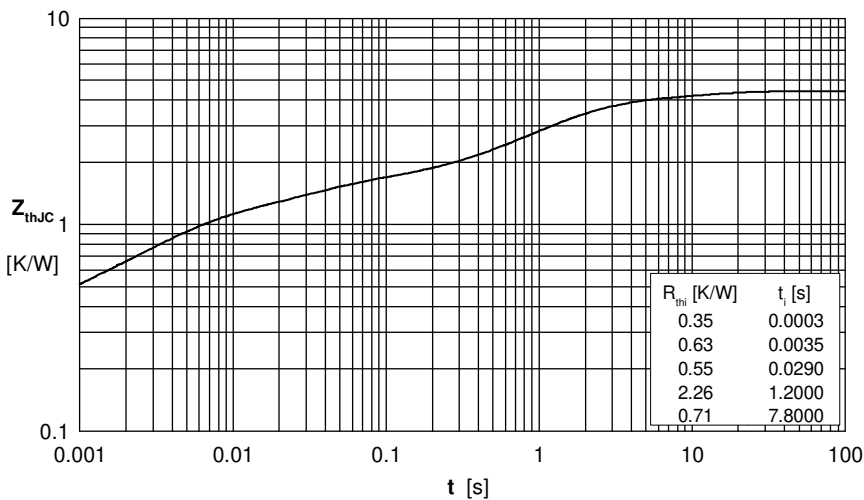


Fig. 6 Transient thermal impedance junction to case